

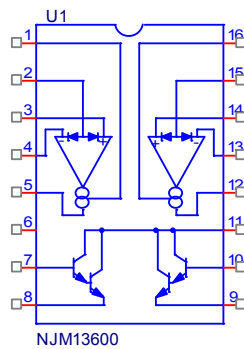
Device Modeling Report

COMPONENTS: OPERATIONAL AMPLIFIER
PART NUMBER: NJM13600
MANUFACTURER: NEW JAPAN RADIO CO., LTD.



Bee Technologies Inc.

Spice Model



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*PART NUMBER: NJM13600
*MANUFACTURER: NEW JAPAN RADIO
*Transconductance OPAMP
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.SUBCKT 13600 Amp Di +IN -IN OUT VSS BUFIN BUFOUT VDD
Vop      1 -IN 0.561m
I1       -IN 0 0.0677n
I2       +IN 0 .64n
D1       DI +IN D11
D2       DI -IN D12
D3       3 VSS D14
D4       VDD 5 D13
D5       VDD 6 D15
D6       9 VSS D16
Q1       7 +IN 2 QAA2
Q2       4 1 2 QAA1
Q3       2 AMP 3 QAA3
Q4       AMP 3 VSS QAA4
Q5       4 5 VDD Q_PVAF1
Q6       8 4 5 Q_PVAF
Q7       7 6 VDD Q_pVAF2
Q8       OUT 7 6 QP_OUT
Q9       OUT 8 9 QN_OUT
Q10      8 9 VSS QAA5
QB1      10 3 VSS BUF_IN
QB2      VDD BUFIN 10 BUF1
QB3      VDD 10 BUFOUT BUF
C1       7 OUT 4.573p
.MODEL d11 D (IS=30E-14 N=1 RS=1m IKF=0 ISR=10E-15)
.MODEL d16 D (IS=10E-15 N=1 RS=1.0000E-3 IKF=0)
.MODEL d15 D (IS=10.000E-15 N=1 RS=1.0000E-3 IKF=0)
.MODEL d14 D (IS=10.000E-15 N=1 RS=1.0000E-3 IKF=0)
.MODEL d13 D (IS=10.000E-15 N=1 RS=1.0000E-3 IKF=0)
.MODEL d12 D (IS=90E-15 N=1 RS=1m IKF=0 ISR=10E-15 CJO=1p)
.model Q_PVAF PNP (IS=10.000E-15 )
.model Q_PVAF1 PNP (IS=10.000E-15)
+ NE=1.5000 BR=21 NR=1 VAR=100 NC=2 NK=.5 )
.model Q_PVAF2 PNP (IS=11.440E-15 BF=100 NF=1 VAF=100
+ NE=1.5000 BR=1 NR=1 VAR=100 NC=2 NK=.5 )
.MODEL Qaa1 NPN (IS=10.000E-15 BF=920 NF=1 VAF=100
+ NE=1.5000 BR=21 NR=1 VAR=100 NC=2 NK=.5 )
.MODEL Qaa2 NPN (IS=10.000E-15 BF=700 NF=1 VAF=100
+ NE=1.5000 BR=21 NR=1 VAR=100 NC=2 NK=.5 RE=0.249)

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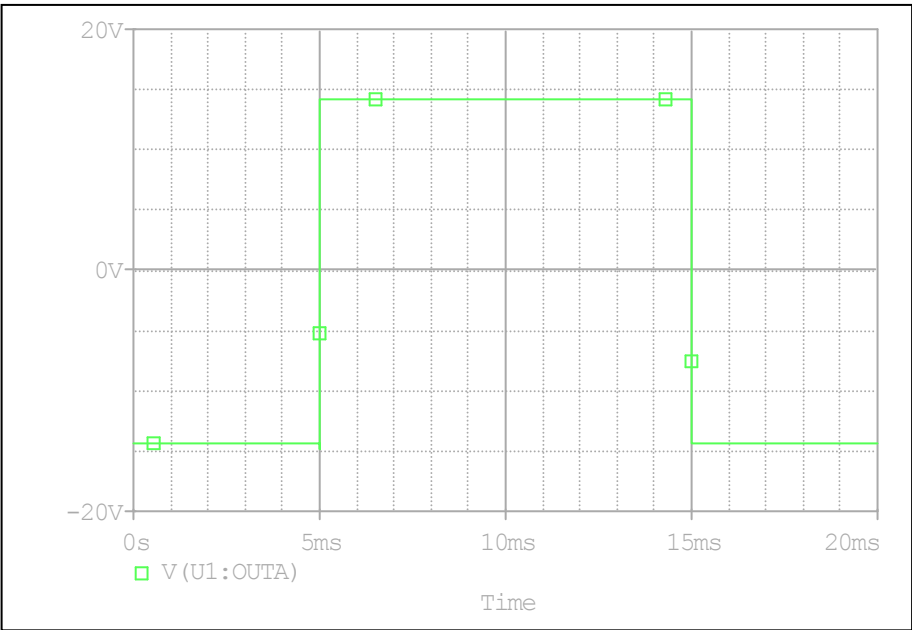
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.model Qaa3 NPN (IS=10.000E-15 BF=100 NF=1 VAF=100
+ NE=1.5000 BR=1 NR=1 VAR=100 NC=2 NK=.5 )
.model Qaa4 NPN (IS=10.000E-15 BF=100 NF=1 VAF=100
+ NE=1.5000 BR=1 NR=1 VAR=100 NC=2 NK=.5 )
.model Qaa5 NPN (IS=11.50E-15 BF=100 NF=1 VAF=100
+ NE=1.5000 BR=1 NR=1 VAR=100 NC=2 NK=.5 )
.MODEL QP_OUT PNP (IS=10.000E-15 BF=100 NF=1 VAF=100
+ NE=1.5 BR=.1001 VAR=100 IKR=10.010E-3 ISC=504E-12
+ NC=1.06252 NK=.56106 RB=.209 RC=0.3970 )
.MODEL QN_OUT NPN (IS=10.000E-15 BF=100 NF=1 VAF=100
+ NE=1.5 BR=52.477 VAR=100 IKR=.40837 ISC=53.671E-12
+ NC=1.8061 NK=.22646 RB=.73666 RC=25.602e-3 )
.MODEL Buf NPN (IS=10.000E-15 BF=100 NF=1 VAF=100
+ NE=1.5 BR=1 NR=1 VAR=10 NC=2 NK=.5 CJE=2p CJC=2p
.MODEL Buf1 NPN (IS=100.000E-12 BF=1590 NF=1 VAF=10
+ NE=1.5 BR=1 NR=1 VAR=100 NC=2 NK=.5 CJE=2p CJC=2p
.MODEL Buf_In NPN (IS=10.0000E-15 BF=100 NF=1 VAF=100
+ NE=1.5000 BR=1 NR=1 VAR=100 NC=2 NK=.5 CJE=2p )
.ENDS

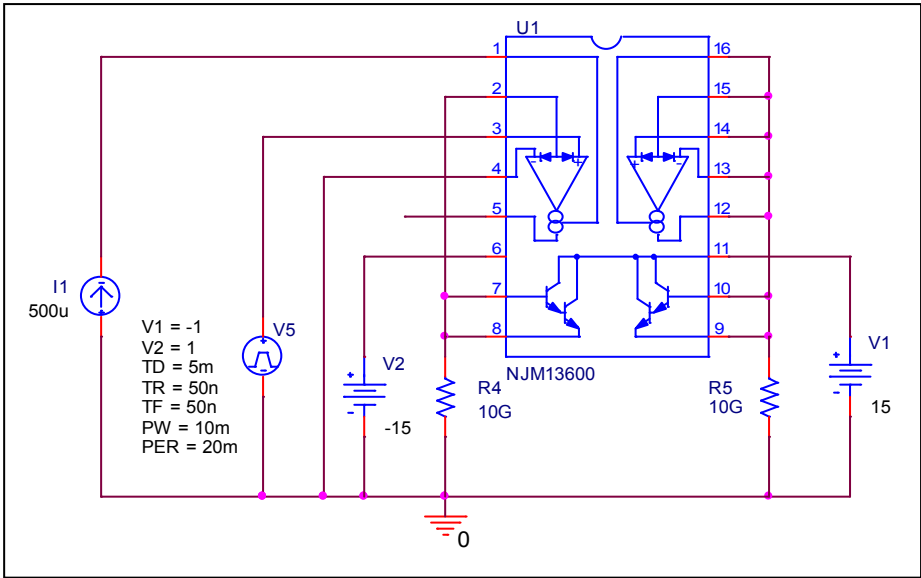
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Output Voltage Positive and Negative

Simulation result



Evaluation circuit

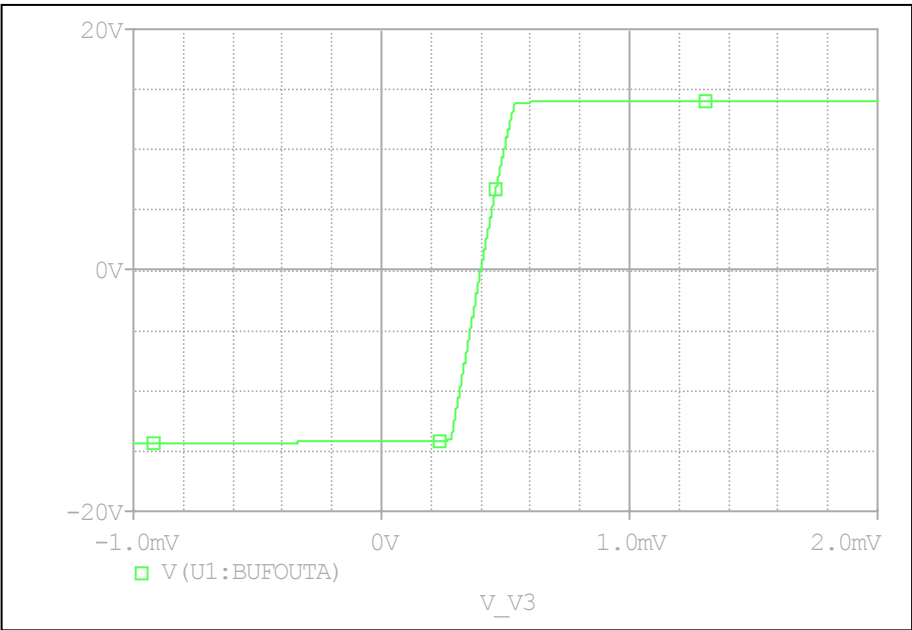


Comparison table

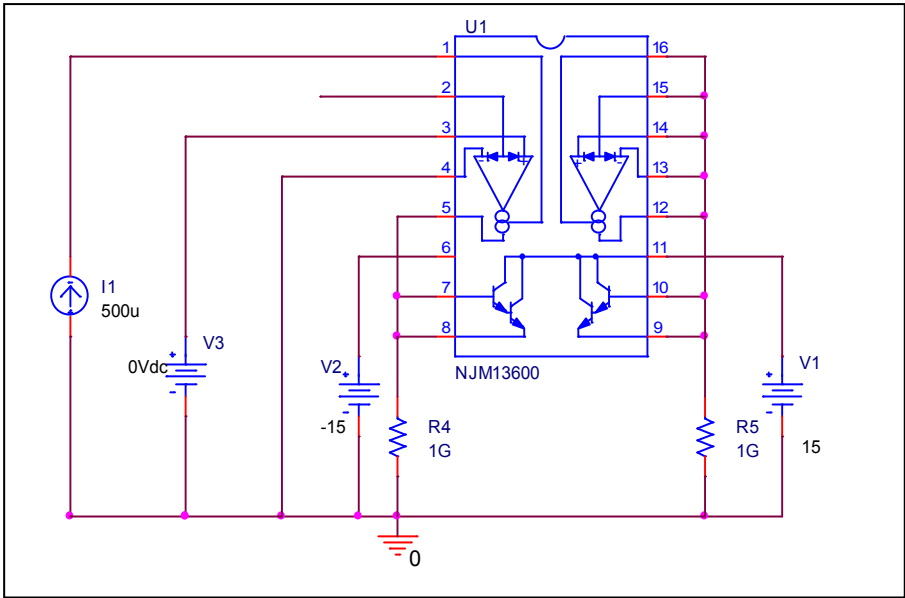
$I_{ABC} = 500\mu A$	Measurement	Simulation	%Error
$V_{op} + (V)$	+14.2	+14.114	-0.606
$V_{op} - (V)$	-14.4	-14.372	-0.194

Input Offset voltage

Simulation result



Evaluation circuit

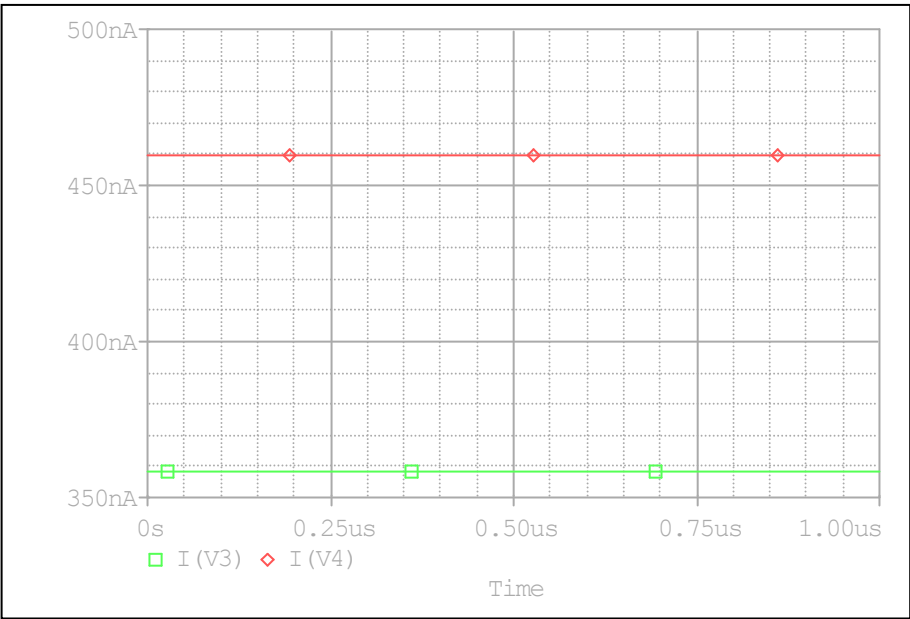


Comparison table

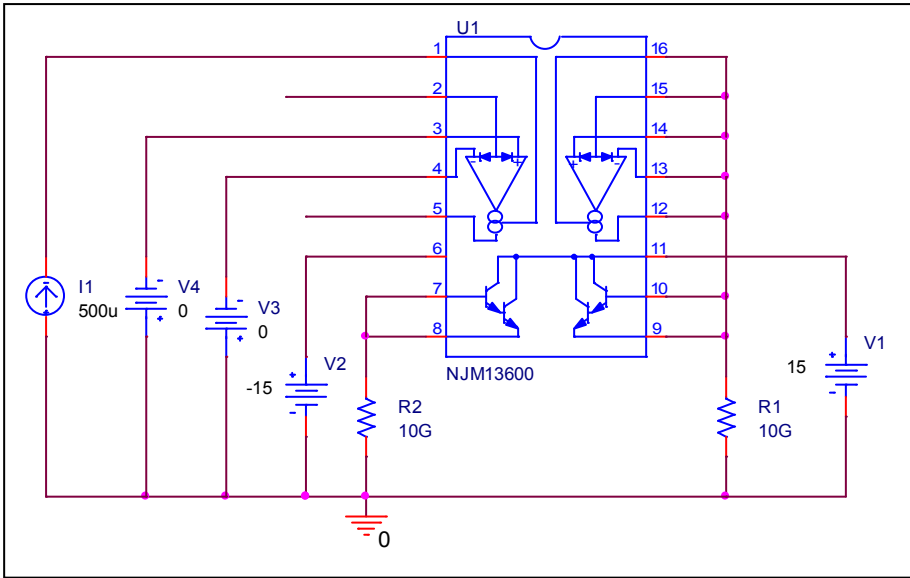
$I_{ABC} = 500\mu A$	Measurement	Simulation	%Error
$V_{IO} \text{ (mV)}$	0.4	0.406	1.500

Input Bias Current and Offset Current

Simulation result



Evaluation circuit

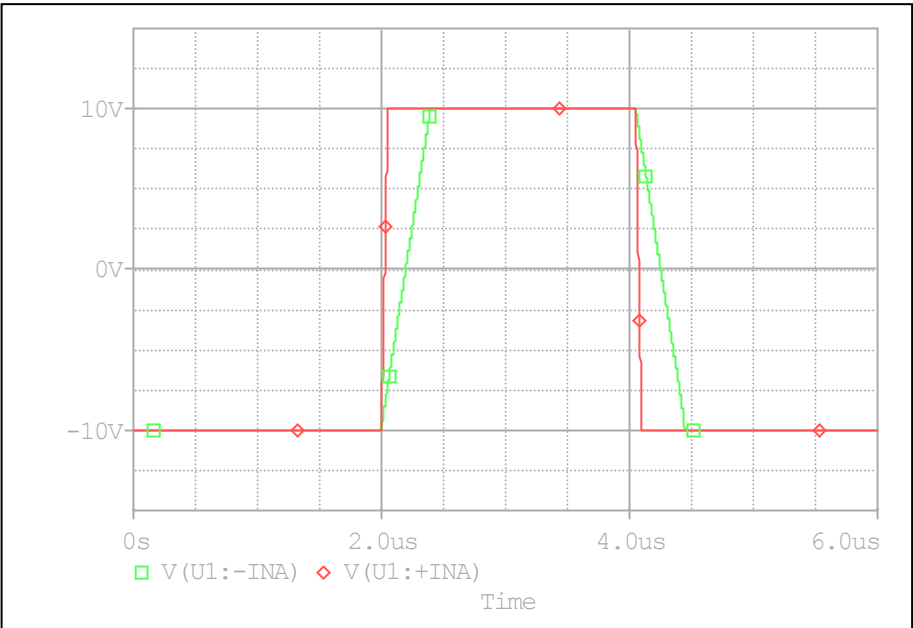


Comparison table

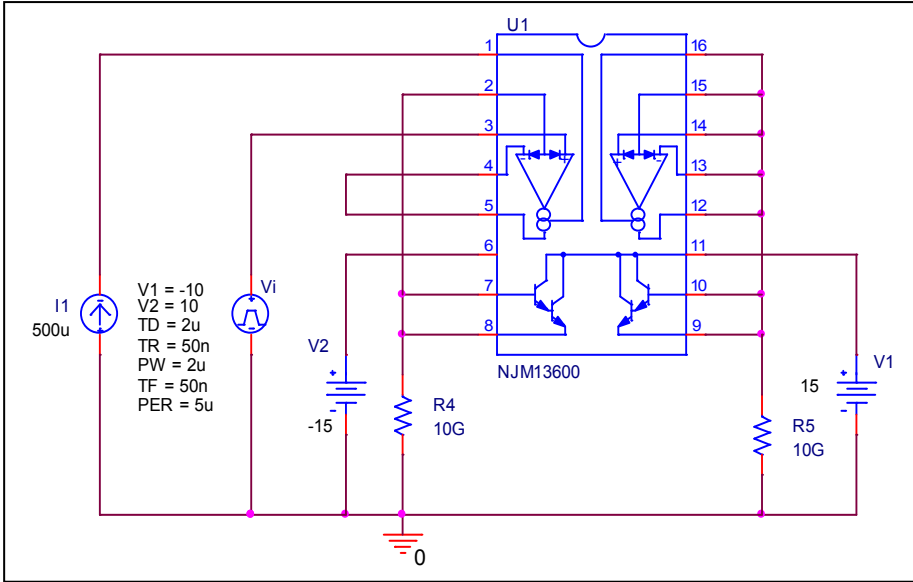
$I_{ABC} = 500\mu A$	Measurement	Simulation	%Error
$I_B (\mu A)$	0.4	0.409	2.250
$I_{IO} (\mu A)$	0.1	0.101	1.000

Slew Rate

Simulation result



Evaluation circuit

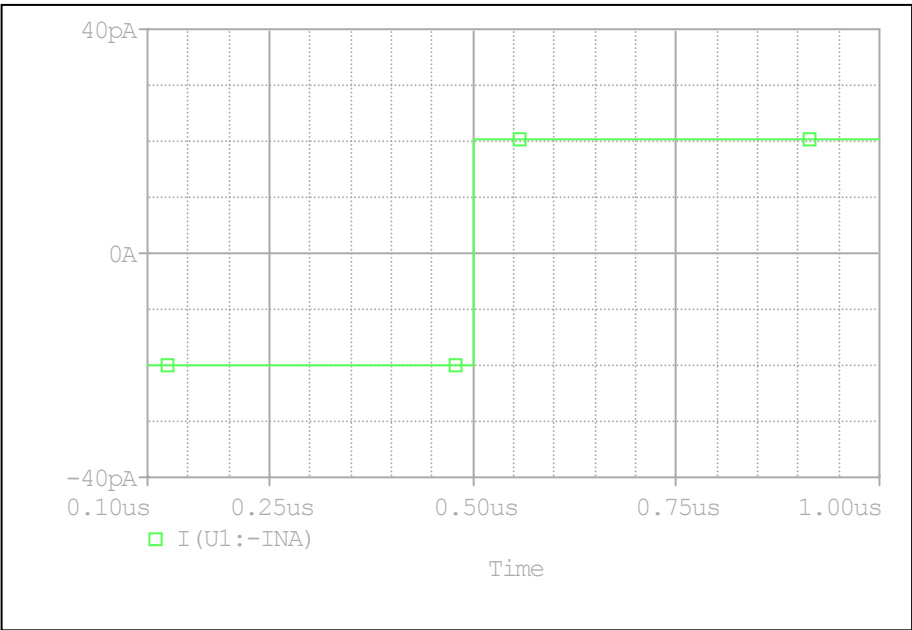


Comparison table

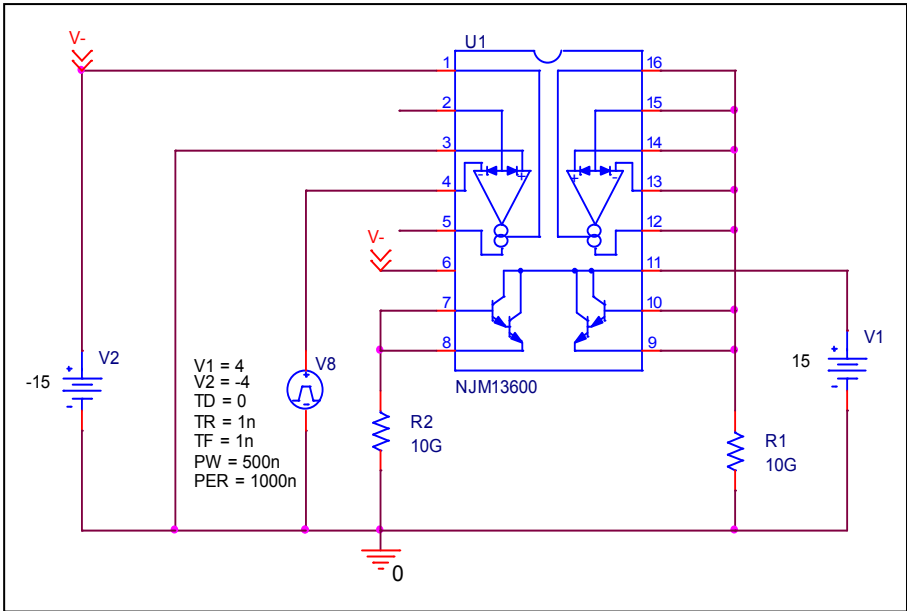
$I_{ABC} = 500\mu A$	Measurement	Simulation	%Error
SR (V/us)	50	49.993	-0.014

Differential Input Current

Simulation result



Evaluation circuit

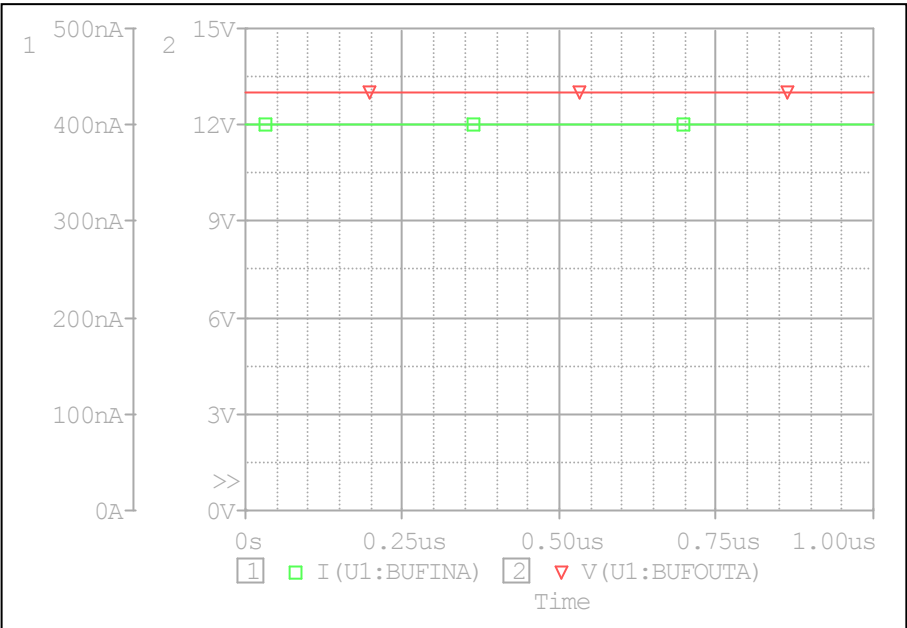


Comparison table

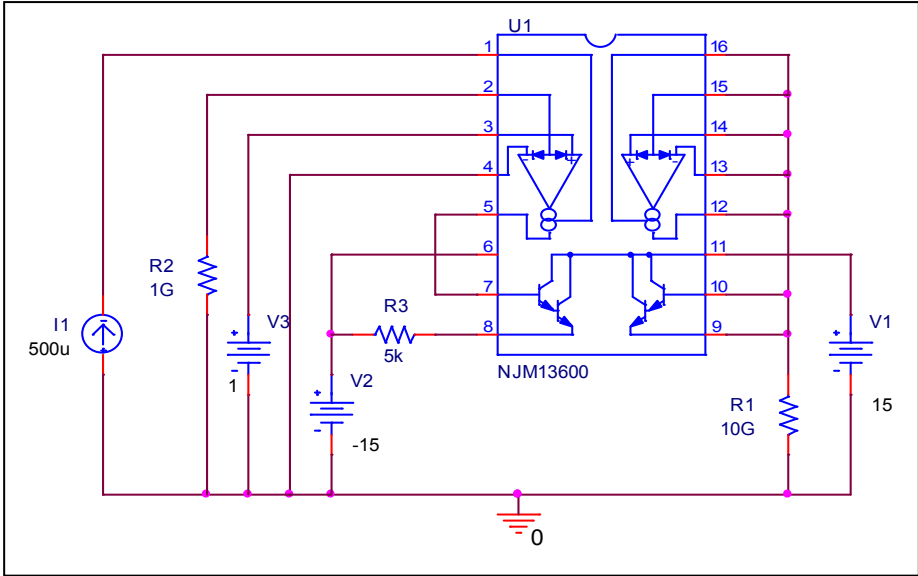
$I_{ABC} = 0\mu A$	Measurement	Simulation	%Error
$I_{ID} \text{ (nA)}$	0.02	0.02	0

Buffer Input Current and Output Voltage

Simulation result



Evaluation circuit

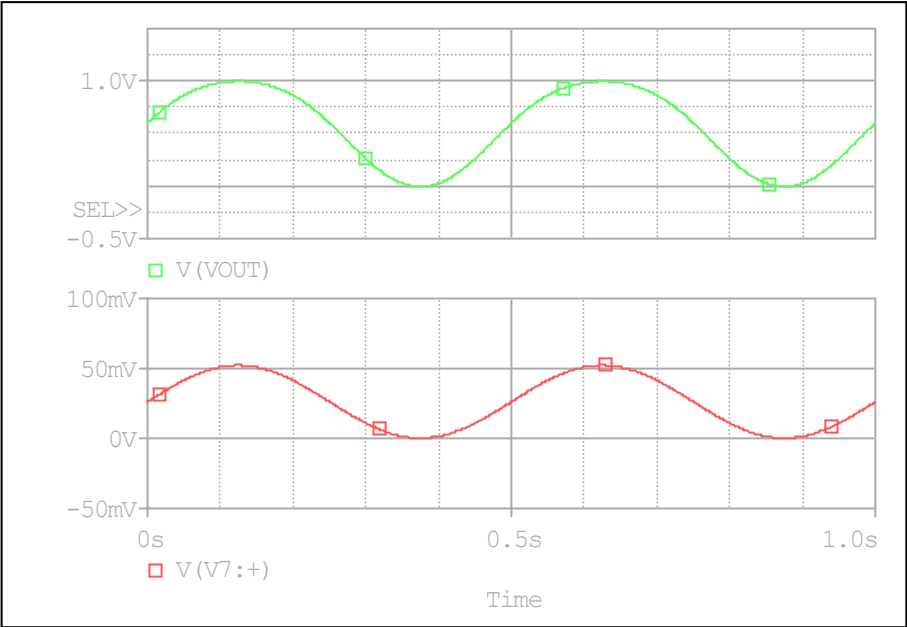


Comparison table

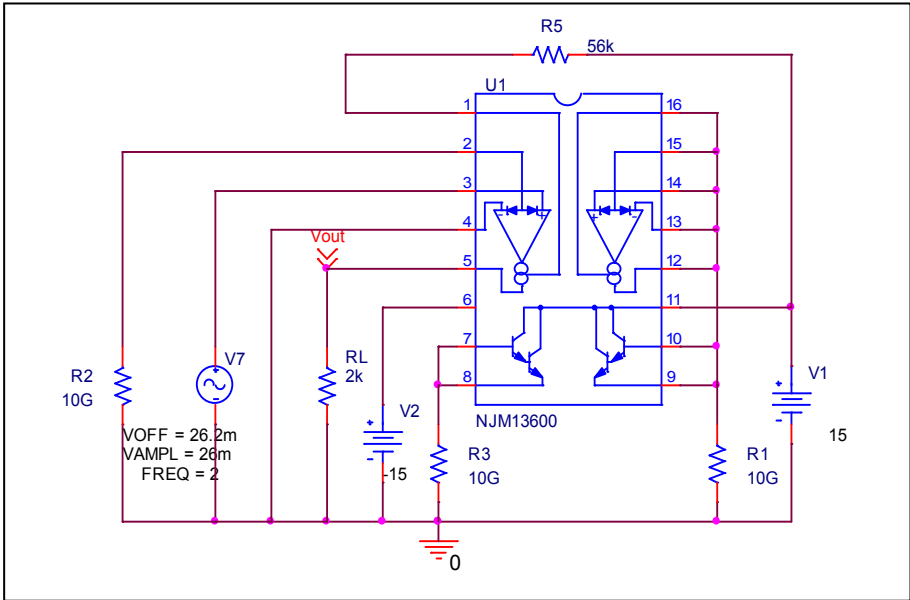
$I_{ABC} = 500\mu A$	Measurement	Simulation	%Error
Buffer Input Current (uA)	0.4	0.4	0
Buffer Output Voltage (V)	13	13.017	0.131

Forward Transconductance

Simulation result



Evaluation circuit



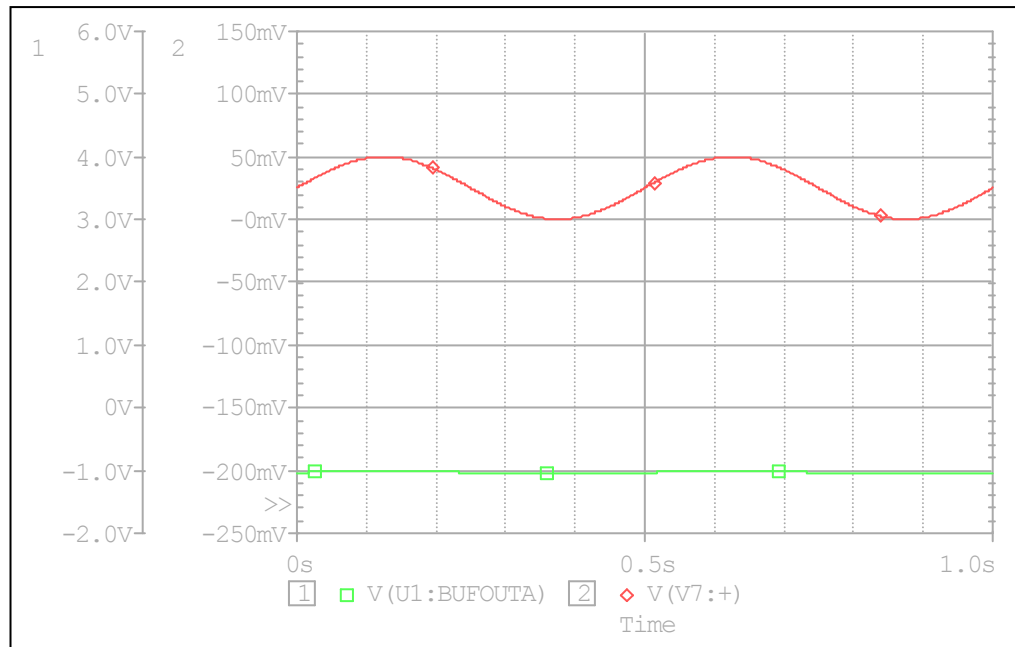
$$g_m = (V_{out}/R_L)/((V_{in+})-(V_{in-})) = (1.0035/2k)/(52m-0) = 9649 \text{ uS}$$

Comparison table

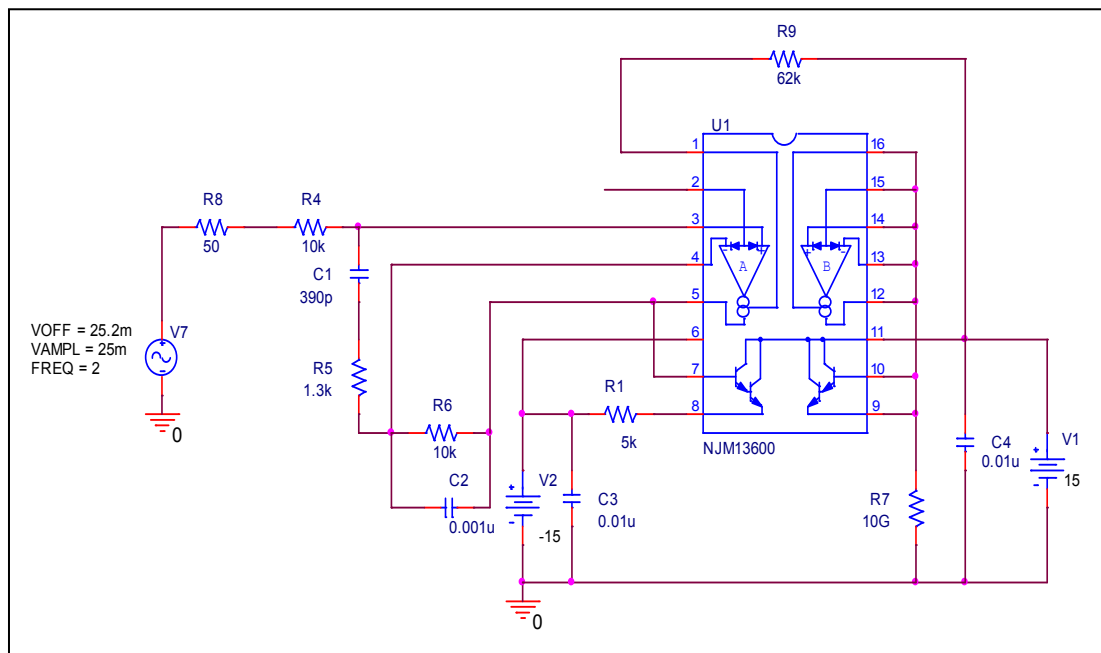
$I_{ABC} = 500\mu A$	Measurement	Simulation	%Error
$g_m \text{ (uS)}$	9600	9649	0.510

Typical Applications

Simulation result



Evaluation circuit



Reference

